## NSN 5961-01-461-7964

Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material:                                      |
|--|
| Plastic  |
| Mounting Method:   |
| Unthreaded hole  |
| Semiconductor Material:                                  |
| Germanium  |
| Voltage Rating In Volts Per Characteristic:              |
| 200.0 breakdown voltage, collector-to-emitter, base open |
| Terminal Type And Quantity:                              |
| 3 uninsulated wire lead                                  |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
|  |
| Demilitarization:  |
| No   |
| Fiig:  |
| A110a0   |
|  |